# D ispersive m easurem ents of superconducting qubit coherence with a fast, latching readout

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The \quantronium " is a superconducting qubit consisting of a split C ooper pair box in which a large tunnel junction is inserted. This circuit has a special bias point where the Larm or frequency is, to rst order, insensitive to uctuations in the bias parameters { the charge of the box island and the phase of the large junction. At this optim al working point, the state of the qubit can be determ ined by dispersive m easurements that probe the second derivative of the state energy with respect to these bias parameters. We use the quantronium phase degree of freedom to perform a non-linear, dispersive m easurement of its inductive response using bifurcation amplication. This novel readout projects the state of the qubit in a few nanoseconds, and its latching property allows us to record the resulting information in a few hundred nanoseconds. We have measured, using this technique, R abioscillations and R am sey fringes with an improved signal to noise ratio and contrast. The speed of this new readout scheme e also opens the door for a new class of experiments which would characterize the relaxation processes associated with the measurement protocol.

#### I. IN TRODUCTION

Superconducting tunnel junction circuits were rst proposed for quantum information processing several years ago, and at present, are the most advanced solid state qubits with the longest measured coherence times [1, 2, 3, 4, 5, 6, 7]. Yet, the physical origin of the noise sources lim iting coherence are still debated, even though the theoretical form alism for treating the e ects of noise in general is well developed [8, 9, 10]. It has been conjectured that impurities or defects found on-chip could act as such noise sources [11]. These parasitic elements may exist in the junction tunnel barriers, the metallic electrodes, the circuit substrate, or in som e com bination thereof. In addition, the shadow-m ask evaporation technique used to fabricatem any superconducting qubits typically generates extra electrodynam ic resonators in close proximity to the qubit junctions [12]. These resonators can have a characteristic frequency comparable to the qubit Larm or frequency, and are thus suspected to decohere the qubit. The precise manner in which a qubit interacts with uncontrolled degrees of freedom in its environm ent depends on the topology of the tunnel junction circuit and how information is written to and read from the qubit. C incuits which have a high degree of symmetry can be signi cantly decoupled from a noisy environm ent [1, 13] when biased at special operating points. The choice of readout scheme is also highly signi cant. Dispersive m easurem ents of the qubit state [14, 15] probe the reactive part of the response of the circuit, and are thus attractive since they m in in ally excite the spurious degrees of freedom described above.

We report the rst coherence measurements of a superconducting qubit with a non-linear dispersive readout. Our approach involves coupling the \quantronium " qubit [1] to a novel superconducting am plier { the Josephson bifurcation am plier (JBA) [16]. The JBA is based on a non-linear electrodynamic resonator with twom etastable oscillation states [17]. In order to perform a readout, the

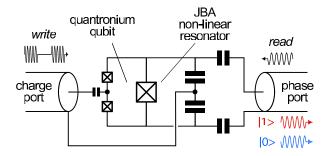


FIG.1: Schem atic of the m easurement setup. The quantronium qubit is a split C ooper pair box with two small Josephson junctions in which a large junction is inserted for readout. This latter junction is shunted by two capacitors in series and form s the non-linear resonator of the JBA readout. The qubit state is manipulated by sending pulses to the charge port, while readout operation is performed by sending a pulse to the phase port and analyzing the phase of re ected signal, which carries inform ation on the qubit state.

resonator is RF-energized to a level where its oscillation state now acts as a sensitive pointer of the qubit state. This technique does not generate any dissipation on chip since the resonator is only damped by circuitry outside the chip, i.e. a 50 transmission line with a matched circulator and ampli er, and enables a high-delity qubit readout with a MHz repetition rate. We have measured Rabioscillations and Ram sey fringes with su cient speed that realtime Itering to correct for drifts in the charge and ux bias becomes possible. A loo, several successive readoutsm ay be performed within the energy relaxation time of the qubit  $(T_1)$ . This gives valuable information on the readout-induced interaction between the qubit and its environment, and accounts for the observed contrast.

## II. THE HAM ILTON IAN OF THE QUANTRON IUM QUBIT W ITH JBA READOUT

The principle of our experiment is schematically depicted in Fig. 1 and is based, as discussed above, on the quantronium qubit, a three junction circuit which is analogous to a one-dimensional atom. The set of three junctions consists of two sm all junctions, which we assume to be identical and have a Josephson energy com parable to the charging energy of the island between them, and a large junction, whose Josephson energy is approximately 100 times larger than that of each small junction. The gauge-invariant phase di erence  $\hat{}$  of the island with respect to the mid-point of the capacitance shunting the large junction is analogous to the position of the electron relative to the nucleus of the atom , while the gauge-invariant phase di erence  $\hat{}$  across the large junction is the absolute position of the nucleus. Neglecting the dissipation induced in the transm ission lines, the total ham illonian of the split C ooper pair box with a JBA resonator is  $\hat{H}(t) = \hat{H}_{box}(t) + \hat{H}_{res}(t)$  with

$$\hat{H}_{box}$$
 (t) = 4E<sub>C</sub>  $\hat{N}$   $\frac{1}{2} + \frac{C_{gU}$  (t)  $\frac{2}{2e}$   $E_{J} \cos \frac{1}{2} \cos^{2}$  ;  $\hat{H}_{res}$  (t) =  $\frac{\hat{Q}^{2}}{2C}$   $E_{J}^{R} \cos^{2}$   $r_{0}I$  (t)

Here,  $\hat{N}$  and  $\hat{Q}$ =2e are the m on enta conjugate to the generalized positions  $\hat{}$  and  $\hat{}$ , respectively. The constants  $E_c$ ,  $E_J$ ,  $E_J^R$ , C and  $C_g$  are the single electron charging energy of the island between the small junctions, the sum of the Josephson energy of the two small junctions, the large junction Josephson energy, the total capacitance shunting the large junction, and the gate capacitance, respectively. Here  $\prime_0 =$  ~=2e is the reduced ux quantum. The control parameters U (t) =  $U_{rf}$  (t) cos t and I (t) =  $I_{rf}$  (t) cos! t are analogous to electrom agnetic probe elds in an atom ic system and induce a charge ex-

citation of the write port and a phase excitation of the read port, respectively. This ham iltonian has been written supposing that the original set of the operate at the optimal bias point where the charge  $\frac{\theta f}{\theta U}$  and the  $ux \frac{\theta f}{\theta I}$  have zero mean value in both the ground jDi and rst excited jLi states of  $\hat{H}_{box}$ . Under these conditions, the qubit is minimally sensitive to charge and ux noise [1].

If we keep these two lowest states in the H ilbert space of the circuit we obtain an e ective qubit ham iltonian

$$\hat{H}_{eff} = \frac{2C_{g}U(t)}{e}E_{CX} \frac{E_{J}}{2}E_{T} + \frac{E_{J}}{2}E_$$

where

$$I_{p} = \frac{S}{\frac{E_{J}^{R}}{I_{0}^{2}C}}$$
$$= \frac{E_{J}}{4E_{J}^{R}}$$
$$= \frac{E_{C}^{R}}{12} = \frac{1}{12}\frac{(e)^{2}}{2C}$$
$$f = I_{0}^{2} \frac{2E_{C}^{R}}{E_{J}^{R}}$$

The photon annihilation operator a is related to ^ by

$$\hat{} = \frac{a + a^{Y}}{E_{T}^{R} = 2E_{C}^{R}}$$

which represents the decomposition of the gaugeinvariant phase di erence into annihilation and creation operators of the \plasm a"m ode whose bare frequency is  $!_p$ . The operators  $_X$  and  $_z$  are the Pauli spin operators and  $E_c^R$  is the single electron charging energy of the readout junction. In this e ective ham iltonian, the expansion of cos ^ is carried out only to the rst anharm onic term, which describes the non-linear resonator dynam ics with su cient accuracy for a bifurcation readout.

Let us describe the role of each term in (1). The rst term describes the in uence on the qubit of the charge port drive which is used to manipulate its state. The second term is the Larm or term  $!_{01} = E_J = \sim$ . We have supposed here that the ratio  $E_J = E_C$  is su ciently small that corrections to the Larm or frequency involving  $E_C$  are small. To model the behavior of qubit samples with an appreciable  $E_J = E_C$  ratio, we would keep higher order terms, yielding renormalized values of the coe cients in

(1). The third term describes the dom inant coupling between the qubit and the resonator. Note that this term commutes with the ham iltonian of the qubit when U = 0, o ering the possibility of quantum non-demolition measurements. The fourth term describes a decrease in the frequency of the resonator when its photon population increases [18]. Finally, the find term describes the excitation of the resonator by the drive current applied through the phase port. When the drive current is increased while its frequency is su ciently below  $!_p$  the system becomes metastable with two possible dynamical states with dienent oscillation amplitudes, i.e. two possible photon populations [16]. We exploit this bistability for our readout, which we describe in the next section.

#### III. QUBIT READOUT

It is clear from the ham iltonian (1) above that the dynam ics of the non-linear resonator depend on the value  $_{\rm Z}$  = 1 corresponding to the state of the qubit. In particular, the small oscillation  $\rho a m a m frequency !_p^e =$ ) varies with the qubit state. We probe the non-!<sub>p</sub> (1 linear resonator by sending down the phase port transm ission line a m icrowave pulse with carrier frequency !, such that the detuning  $\frac{3}{20}!_{p}$  $! = !_{p}$ ! > where Q is the quality factor of the plasm a resonance [17]. In our circuit, the damping of the plasma resonance arises from the characteristic transmission line impedance  $Z_c = 50$  and thus  $Q = Z_c C !_p ' 10 20$ . For this value of detuning, when ramping up the drive current I<sub>rf</sub> the resonator switches from one dynamical state to another when

### $I_{rf} > I_{B} !;!_{p}^{e}$

where  $I_B$  is the bifurcation current with expressions given in [19]. Therefore, by choosing the maximum pulse am - plitude

$$I_{B} [!;!_{p}(1)] < I_{rf}^{max} < I_{B} [!;!_{p}(1+)]$$

we can determ ine, by measuring if the resonator has switched or not, whether the qubit was in state Di or jli.

The dynam ical states of the resonator di er in both the am plitude and phase of the forced oscillations at frequency !. In this work, we have chosen to use a re ectom etry setup in which all the inform ation about the resonator state is carried by the re ected drive signal phase

. This last property occurs because the probed circuit is not intrinsically dissipative (in absence of quasi-particles, which is very well realized in our measurements) and the power relected from the chip is equal to the incident power in steady state. A further advantage of our non-linear resonator is that the switching is strongly hysteretic. Once a switching event has occurred we can decrease the drive current  $I_{\rm rf}$  to a value which, while much

sm aller than  $I_B$  [!; !  $_p$  (1 )], is still higher than the reverse bifurcation \retrapping"current  $I_B$ . This latching property conserves the inform ation about the qubit state acquired during a sm all time interval  $_m$  in the resonator and allow s us to probe the relected phase during a time typically longer than  $_m$ .

In Fig. 2, we present a typical histogram of the reected drive signal phase corresponding to a drive current Irf which causes the resonator to switch, on average, half of the time. The histogram has 800,000 counts acquired in 200 m s. For qubit m easurem ents shown later, histogram s with only 10,000 are used. The shape of the readout pulse used is schem atically shown in the inset of Fig. 2. The rise time of the pulse is typically 20 40 ns. the maximum current  $I_{rf}^{max}$  is applied for 40 120 ns and the latched section lasts 120 ns, during which the recorded re ected signal phase is bim odal, with values di ering by about 124. W e have chosen the phase reference so that the value =  $l_{DW}$  = 62 corresponds to the resonator in its initial state, while =  $_{high} = 62$ corresponds to the resonator having switched. We de ne the switching probability  $P_{switch} I_{rf}^{max}$ ; !; h j<sub>z</sub> j i, where j i is the state of the qubit, as the weight of the histogram that lies above  $=\frac{\log + \log \log 2}{2} = 0$ .

#### IV. COHERENCE RESULTS

W e now present experim ental results on two di erent qubit sam ples whose characteristic param eters are listed in Table I, along with a sum mary of our results. In the gures that follow, we only show data for sam ple A.

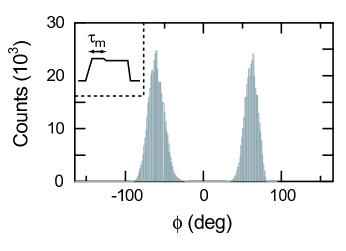


FIG.2: Typical histogram of the phase of the rejected signal in the JBA readout when the maximum rf drive current is chosen so that the resonator switches approximately half of the time. The switching probability  $P_{switch}$  is dened as the fraction of the histogram lying above = 0. The inset shows schematically the envelope of the readout pulse sent to the phase port. The qubit in uences the switching probability during the time interval m which here was 40 ns.

Sample	! <sub>01</sub> =2 (GHz)	E <sub>J</sub> =E <sub>C</sub>	T <sub>1;typical</sub> (s)	T <sub>2</sub> (ns)	T <sub>echo</sub> (ns)	exp	calc	exp= calc
А	9 <b>:</b> 513	2:7	4:0	320	400 500	<b>:</b> 48	<b>:</b> 70 <b>:</b> 05	:69
В	18:989	6 <b>:</b> 0	1:0	300	300	:61	<b>:</b> 70 <b>:</b> 05	<b>:</b> 87

We rst characterized our readout by measuring  $P_{\,sw\,itch}$  as a function  $I_{\rm rf}^{m\,ax}$  and j i, as shown in Fig. 3. The blue circles correspond to the qubit in its ground state, obtained by letting the qubit relax spontaneously, while the red circles correspond to the qubit in its st excited state obtained by applying a pulse, which will be discussed below. An important remark is that only a slight change in shape of  $P_{\text{sw itch}} \quad I_{\text{rf}}^{\text{m ax}} \quad \text{between the}$ two qubit states is observed, which indicates that the switching process itself does not contribute strongly to the relaxation of the qubit. In cases where the readout is suspected to induce signi cant relaxation, the switching probability curve for the qubit excited state displays a pronounced kink and can be obtained by a weighted average of the observed curve for the ground state and the prediction for the excited state [7, 20]. The discrimination power of the qubit readout is de ned as

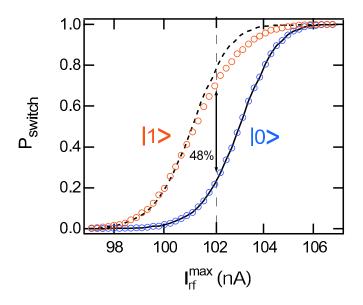


FIG.3: Switching probability as a function of maximum drive current and qubit state for sample A.D otted line represents value of drive current at which maximal discrimination power is observed. The width in current of the curves is in reasonable agreement with numerical simulations (data not shown). The solid line connects the observed data points in the jDi state and the dashed line is a copy of the solid line horizontally shifted to overlap the jLi state data at low values of  $P_{\rm switch}$ .

$$= \max_{\substack{I_{we}^{max} \\ I_{we}^{max}}} \mathbb{P}_{sw \text{ itch}} (h_{z} i = 1) \mathbb{P}_{sw \text{ itch}} (h_{z} i = 1)]$$

and its observed (  $_{\rm exp}$ ) and predicted ( $_{\rm calc}$ ) values are given in Table I. Num erical simulations [21] of the full circuit have been used to compute the predicted values of . Note that several competing factors enter this calculation, yielding similar values for samples A and B. The error bars relact uncertainties in the values of stray reactances on chip and the precise resonator temperature.

The observed discrim ination power is about 15 30 % sm aller than expected, and we attribute this loss to spurious on-chip defects. In a set of experiments to be described in a later publication, we used two readout pulses in succession to determ ine that a 15 30% loss of qubit population occurs even before the resonator is energized to its operating point. As photons are injected into the resonator, the e ective qubit frequency is low ered due to a Stark shift via the phase port [22]. W hen the Stark shifted frequency coincides with the frequency of an onchip defect, a relaxation of the qubit occurs. Typically, the qubit frequency spans 200 300 M H z before the state of the qubit is registered by the readout, and 3 4 spurious resonances are encountered in this range.

For future measurements, we have developed a new method to counter this elect. When applying a readout pulse via the phase port, we apply a compensating pulse via the charge port which Stark shifts the qubit to higher frequencies. When balancing these pulses, we have successfully reduced the net frequency shift to below 20M Hz and have minimized population loss to defects before the resonator switches. To increase the expected discrimination power to unity, we must use samples with either a larger qubit  $E_J$  or a stronger phase coupling between the qubit and readout resonator. The latter can be accomplished by using a resonator with two Josephson junctions in series.

Having characterized our readout discrimination power, we perform ed a series of experiments to assess the coherence of our qubit, namely the measurements of  $T_1, T_2, T_{echo}$  and  $f_2$ . These times characterize the decay of the excited state population after a pulse, the decay of Ram sey fringes, the decay of the echo signal after a (; =2; ) pulse sequence and the decay of the Rabi oscillations, respectively.

We rst applied to the charge port a pulse at the Larmor frequency  $!_{01}$  of varying duration and amplitude

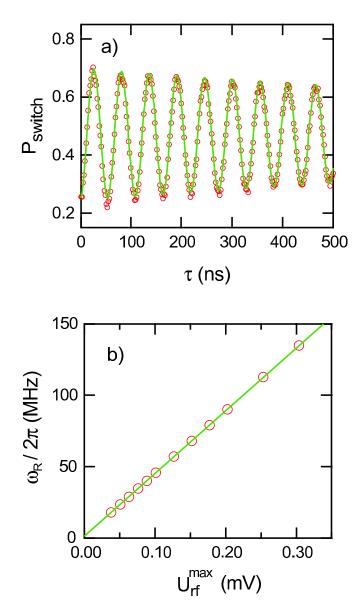


FIG. 4: a) Rabi oscillations of the switching probability of qubit sample A as a function of the duration of a square pulse applied on the gate with maximum amplitude  $U_{rf}^{m\,ax} = 0.12 \text{mV}$ . Solid green curve is an exponentially decaying sinusoidal t with  $\mathbf{f}_2 = 1.6$  s. Total acquisition time is 3m n and duty cycle is 16 s, set by  $T_1$  (see below). b) Rabi oscillation frequency measured in (a) as a function of  $U_{rf}^{m\,ax}$ . G reen line is expected linear dependence.

U  $_{rf}^{max}$ , which performs a rotation of the qubit about  $_{X}$ , followed by a readout pulse on the phase port. The resulting R abi oscillations in the switching probability signal are plotted in Fig. 4a for varying and xed U for a N ear = 0 we observe the P<sub>switch</sub> corresponding to qubit being in the jDi state. As the pulse length increases, P<sub>switch</sub> increases, goes through a maximum where the qubit is purely in the jDi state, de ning at this point the length of a pulse. The switching probability then decreases back to the jDi state value, indicating a full 2 rotation

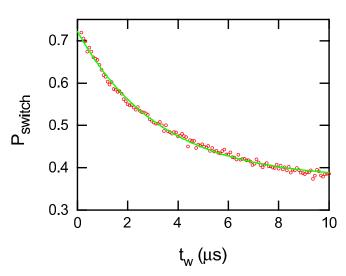


FIG.5: Decay of the excited state switching probability after preparing the qubit in the excited state by a pulse, as a function of the waiting time  $t_w$  between the preparation pulse and the readout pulse. D ata for sample A. Solid green curve is an exponential twith a 32 s decay constant.

of the B loch vector. This pattern repeats itself but with diminishing contrast. The decay time  $f_2^{e}$  is in the range 0.8 1:7 s depending on the sample and precise biasing condition. The Rabi oscillation frequency  $!_{R}$  is plotted as a function of  $U_{rf}^{max}$  in Fig. 4b. A linear dependence of  $!_{R}$  with  $U_{rf}^{max}$  is observed, in agreement with theory. The shortest pulse we generated was 2 ns long, and was used in the echo experiments described below.

Having calibrated the pulse, we then performed a qubit energy relaxation measurement by introducing a waiting time  $t_w$  between the pulse and the readout pulse. The decay of  $P_{switch}$  with  $t_w$ , shown in Fig. 5, is well tted by a single exponential, de ning T. For sample A,  $T_1$  was in the range 2:5 5 s, and for sample B,  $T_1$  was between 1:0 1:3 s. The values of  $T_1$  obtained with our dispersive readout are comparable with the results of V ion et al. [1], and are signing cantily shorter than the values expected from coupling to a well thermalized 50 m icrow ave environment shunting the qubit. The loss mechanisms giving rise to the observed energy relaxation are not understood at this time.

Following measurements of the qubit energy relaxation, we performed a Ram say fringe experiment to determ ine the phase coherence of the qubit. In this experiment, two =2 pulses were applied to the charge port of the qubit at a frequency 10 20M Hz detuned from  $!_{01}$  followed by a readout pulse on the phase port. A free evolution time t was introduced between the two

=2 pulses. In Fig. 6,  $P_{sw itch}$  is plotted as a function of t. In the Ram sey sequence, the rst =2 pulse tips the B loch vector from the north pole to the equatorial plane. D uring the time t, the B loch vector precesses around the equatorial plane and is then rotated again by the second =2 pulse. For t = 0, the two =2 pulses back to

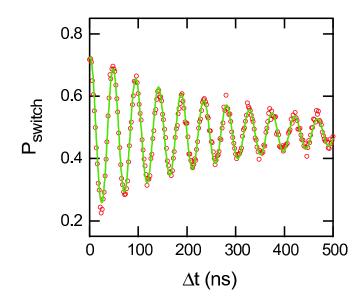


FIG. 6: Ram sey fringes obtained with two =2 pulses separated by the time interval t. The pulse frequency was detuned from the Larm or frequency by 20M Hz. The green curve is a exponentially decaying sinusoid t. The decay time  $T_2$  is 320ns. Same acquisition conditions as in Fig. 4.

back act as a single pulse and the observed value of P<sub>switch</sub> corresponds to the qubit being in the jli state. As tincreases, P<sub>switch</sub> decreases until it reaches the value corresponding to the qubit being in the Di state, corresponding to a free evolution time t in which the Bloch vector makes a rotation in the equatorial plane. The switching probability then continues to increase for larger values of tuntil it reaches a maximum value, corresponding to a time t where the B loch vector m akes a full 2 rotation in the equatorial plane. This oscillatory pattern then repeats but with decreasing contrast corresponding to the loss of phase coherence with time. The Ram sey fringes decay in a time T<sub>2</sub> which has a com ponent due to energy relation and one due to pure dephasing:  $1=T_2 = 1= (2T_1) + 1=T_1$ , where T<sub>1</sub> represents pure dephasing. In our measurements,  $T_2$  is dominated by pure dephasing. For sample A ,  $T_2 = 320$  ns, and for sam ple B,  $T_2 = 300$  ns.

In order to correct dephasing of the qubit due to low frequency noise [2, 23], we perform ed an echo experim ent in which we inserted a pulse in the middle of the two =2 pulses of the R am sey sequence. A set of R am sey fringes and its corresponding echo decay are shown in Fig. 7 for sample A. For this sample, the decay constant was increased to 400 500 ns using the echo technique. For sam ple B, the echo technique did not increase the phase coherence time. We believe that for sample B, which has a large ratio of  $E_J = E_C$  and is protected from 1=f o set charge noise, the dom inant source of dephasing is due to broadband noise em anating from residual photons in our readout resonator [24], thus explaining the ine cacy of the echo sequence. It is possible that the 50 environm ent shunting the qubit on the phase port side was

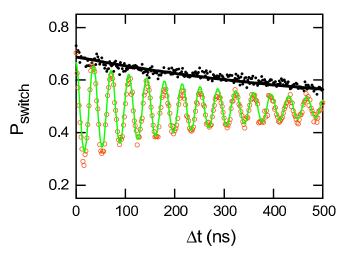


FIG.7: Result of an echo experim entwhere a pulse was kept in the middle of the two =2 pulses separated by interval t (black dots). The corresponding R am sey fringe data is show n with red circles. The thick black curve is an exponentially decaying t.

not fully them alized to the refrigerator temperature of 10 m K. For sample A, where an improvement was observed with the echo sequence, there are likely two contributing factors. First, the ratio  $E_J = E_c$  is much smaller and o set charge noise played a stronger role. The low frequency component of this noise can be corrected using an echo sequence. Second, we added more cryogenic attenuation in the transmission lines directly coupling to the phase port to reduce the resonator temperature, thereby potentially reducing the number of excess photons in the readout resonator and their associated dephasing.

#### V. CONCLUSION

In conclusion, we have successfully in plan ented a nonlinear dispersive readout of the quantronium qubit using the Josephson B ifurcation Ampli er. The readout speed and discrimination power show a signi cantim provement when compared with the DC switching readout used in the original quantronium measurements [1]. Perhaps even more important, in the present readout scheme, the totalmeasurement time is much smaller than  $T_1$ , and it is possible to carry out experiments with multiple readout pulses to determine the information ow during a qubit readout and to account for any losses in qubit population. This important aspect can be used to determine the degree to which the measurement is quantum nondem olishing, and will be described in later publications.

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